## NSN 5961-01-010-1556

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-010-1556 **Inclosure Material:** Glass **Overall Length:** 0.600 millimeters **Overall Diameter:** 1.700 millimeters **Function For Which Designed:** General purpose Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-200aa **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 300.00 amperes forward current, average absolute **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0